AND POWER OF ATTORNEY

DECLARATION U.S.A.

FOR ATTORNEYS' USE ONLY ATTORNEYS' DOCKET NO. P69337US0

ALL PATENTS, INCLUDING DESIGN FOR APPLICATION BASED ON PCT; PARIS CONVENTION; NON PRIORITY; OR PROVISIONAL APPLICATIONS

	original, first and	s a below named inventor, i declare that my residence, post office address and calzensmip are stated below next to my name, the information given herein is true, that i believe that i am the injunal, first and joint inventor (if plural inventors are named below at 201-203, or on additional sheets attached ereto) of the subject matter which is claimed and for which patent is sought on the invention entitled:								
101	ME	METHOD OF FORMING METAL LINE LAYER IN SEMICONDUCTOR DEVICE								
102	which is describ	bed and claimed in: PCT International Application			No.			filed		
ш	_	X the attached specification the specification in application								
	ino andano	·	licable) and amended on	d specification, including the claims, as amended by any ame						
	I hereby state th	at I have reviewed and unders	•				mendment referred to at	pove.		
	I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, §1.56. I hereby claim foreign priority benefits under Title 35, United States Code, §119 (a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identificant any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed: Prior Foreign Application(s) Priority Claimed									
	2003-49249				18/07/2003			_ X		
	(Number)				(Day/Month/Year Filed)			Yes	No	
103	(Number)	Number) (Country)			(Day/Month/Year Filed)			Yes	No	
Ц	(Number)	(Country)				(Day/Month/Year Filed)			No	
\$	I hereby claim th	ne benefit under Title 35, Unite	§119(e) of any United Sta	Inited States provisional application(s) listed below:						
Ц	Application No.			ng Date	·	plication No.		Filing Date		
105	I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose information which is									
ــــا	(A	pplication Serial No.)		(Filin	ng Date)		(Status:)	patented, pending, aband	doned)	
POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorneys (Registration No.) to prosecute this application, receive and act on instructions										
from my agent, and transact all business in the Patent and Trademark Office connected therewith. HARVEY B. JACOBSON, JR. (20,851); JOHN CLARKE HOLMAN (22,769); MARVIN R. STERN (20,640); ALLEN S. MELSER (27,215); MICHAEL R. SLOBASKY (26,421); JONATHAN L. SCHERER (29,851);										
JOHN CLARKE HOLMAN (22,769); MARVIN R. STERN (20,640); ALLEN S. MELSER (27,215); MICHAEL R. SLOBASKY (26,421); JONATHAN L. SCHERER (29,851); IRWIN M. AISENBERG (19,007); WILLIAM E. PLAYER (31,409); YOON S. HAM (45,307) and NATHANIEL A. HUMPHRIES (22,772)									OTTER(20,001),	
	SEND CC	RRESPONDENCE TO:				DIRECT TELEPH				
		Or				(please use		se Attorney's Docket No.) (202) 638-6666		
			N HOLMAN D LIABILITY COMPA	ANY .		JACOBSON HOLMAN				
			STREET, N.W.				AL LIMITED LIABILITY COMPANY			
L			N, D.C. 20004					<u></u>]		
*Inv		nust include at least one u	nabbreviated	first or middle name.	GIVEN NAME			MIDDLE NAME		
1	OF INVENTOR	JLL NAME * FAMILY NAME * INVENTOR LEE			Joon					
ı ⊦								Hyeon COUNTRY OF CITIZENSHIP		
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티	Cheongjoo-Shi OST OFFICE POST OFFICE ADDRESS				Republic of Korea			E OR COUNTRY		
	ADDDECC	Hynix Semiconducto					7.7			
		Hynngjeong-Dong, Heungdeok-Ku, Cheongjoo-Shi, Chungcheongbuk-Do, Republic of Korea			Cheongjoo-Shi Ro		Repu	ıblic of Korea	361-480	
	FULL NAME * FAMILY NAME				GIVEN NAME			MIDDLE NAME		
	OF INVENTOR									
202	RESIDENCE & CITIZENSHIP	CITY	(STATE OR FOREIGN COUNTRY			COUNTRY OF CITIZENSHIP		
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	FULL NAME * OF INVENTOR	L NAME * FAMILY NAME NVENTOR			GIVEN NAME			MIDDLE NAME		
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furth	er that these st	t all statements made here atements were made with of Title 18 of the United S	the knowled	ge that willful false sta	atements and the li	ke so made are pu	nishable by	fine or imprisonment	or both,	
SIC	SNATURE OF I	NVENTOR 201" Jaon Hy	eon, Læ	SIGNATURE OF INV	ENTOR 202* SIGNATURE			OF INVENTOR 203*		
DATE: October 1, 2003 DATE:							DATE:			
Additional inventors are named on separately numbered sheets attached hereto.										